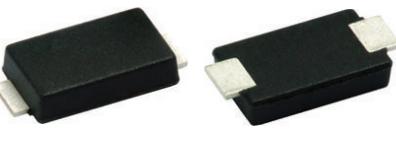


## Hyperfast Rectifier, 1 A FRED Pt®

### eSMP® Series



Top View

Bottom View

### SlimSMA HV (DO-221AC)

Cathode ○ —► Anode

### LINKS TO ADDITIONAL RESOURCES



### FEATURES

- Minimum creepage distance 3.2 mm guaranteed by design
- Comparative Tracking Index: CTI  $\geq$  600
- Hyperfast recovery time, reduced  $Q_{rr}$ , and soft recovery
- 175 °C maximum operating junction temperature
- Specified for output and snubber operation
- Low forward voltage drop
- Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified, meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)

AUTOMOTIVE GRADE



RoHS  
COMPLIANT  
HALOGEN  
FREE

### DESCRIPTION / APPLICATIONS

State of the art hyperfast recovery rectifiers specifically designed with optimized performance of forward voltage drop and hyperfast recovery time.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness, and reliability characteristics.

These devices are intended for use as clamp, snubber and freewheeling diode in a flyback aux power supplies, bootstrap and desaturate for HV MOSFET and IGBT driver, high frequency rectifiers in a cuk and sepic circuit for LED lighting.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce power dissipation in the switching element.

### MECHANICAL DATA

**Case:** SlimSMA HV (DO-221AC)

Molding compound meets UL 94 V-0 flammability rating

**Terminals:** matte tin plated leads, solderable per J-STD-002

**Polarity:** color band denotes cathode end

PRIMARY CHARACTERISTICS	
$I_{F(AV)}$	1 A
$V_R$	1200 V
$V_F$ at $I_F$	1.45 V
$t_{rr}$	50 ns
$T_J$ max.	175 °C
Package	SlimSMA HV (DO-221AC)
Circuit configuration	Single

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Peak repetitive reverse voltage	$V_{RRM}$		1200	V
Average rectified forward current	$I_{F(AV)}$	$T_{sp} = 139$ °C, DC conduction	1	A
Non-repetitive peak surge current	$I_{FSM}$	$T_J = 25$ °C, 8.3 ms sine pulse	14	
Operating junction and storage temperatures	$T_J, T_{Stg}$		-55 to +175	°C

ELECTRICAL SPECIFICATIONS ( $T_J = 25^\circ\text{C}$ unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	$V_{BR}, V_R$	$I_R = 100 \mu\text{A}$	1200	-	-	V
		$I_F = 1 \text{ A}$	-	1.85	2.30	
		$I_F = 1 \text{ A}, T_J = 125^\circ\text{C}$	-	1.55	1.75	
		$I_F = 1 \text{ A}, T_J = 150^\circ\text{C}$	-	1.45	1.65	
Forward voltage drop	$V_F$	$V_R = V_R \text{ rated}$	-	-	2	$\mu\text{A}$
		$T_J = 125^\circ\text{C}, V_R = V_R \text{ rated}$	-	-	20	
Reverse leakage current	$I_R$	$V_R = 1200 \text{ V}, 1 \text{ MHz}$	-	2.5	-	$\text{pF}$
		$V_R = 4 \text{ V}, 1 \text{ MHz}$	-	5.5	-	
Junction capacitance	$C_T$					

DYNAMIC RECOVERY CHARACTERISTICS ( $T_J = 25^\circ\text{C}$ unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Reverse recovery time	$t_{rr}$	$I_F = 0.5 \text{ A}, I_R = 1 \text{ A}, I_{rr} = 0.25 \text{ A}$	-	40	50	ns
		$T_J = 25^\circ\text{C}$	-	91	-	
		$T_J = 125^\circ\text{C}$	-	120	-	
Peak recovery current	$I_{RRM}$	$T_J = 25^\circ\text{C}$	-	3.0	-	A
		$T_J = 125^\circ\text{C}$	-	4.0	-	
Reverse recovery charge	$Q_{rr}$	$T_J = 25^\circ\text{C}$	-	105	-	nC
		$T_J = 125^\circ\text{C}$	-	200	-	

THERMAL AND MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	$T_J, T_{Stg}$		-55	-	175	°C
Thermal resistance, junction to mount	$R_{thJM}^{(1)}$	Device mounted on PCB with 2 x 3.5 mm soldering lands	-	20	23	°C/W
Thermal resistance, junction to ambient	$R_{thJA}$	Device mounted on PCB with recommended pad size	-	120	-	°C/W
Approximate weight			0.032			g
Marking device		Case style SlimSMA HV (DO-221AC)	1X12			

**Note**

<sup>(1)</sup> Thermal resistance junction to mount follows JEDEC® 51-14 transient dual interface test method (TDIM)

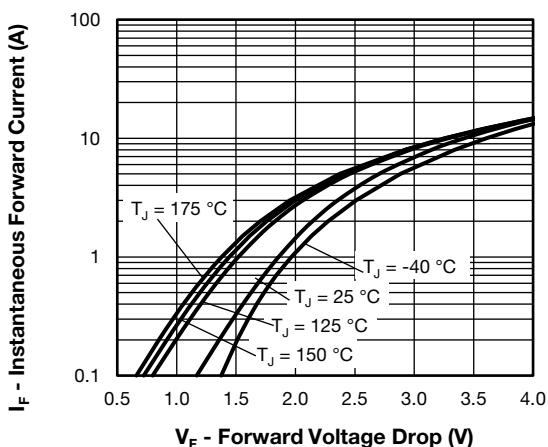


Fig. 1 - Typical Forward Voltage Drop Characteristics

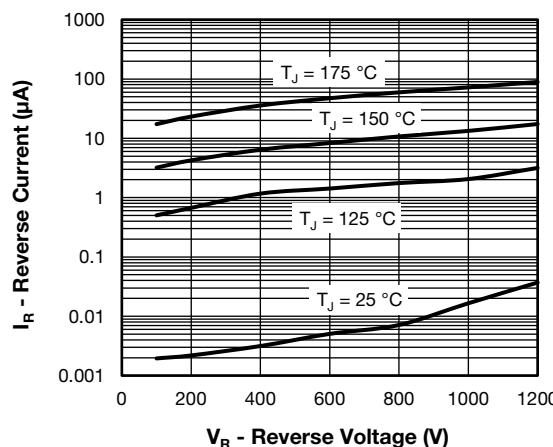


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

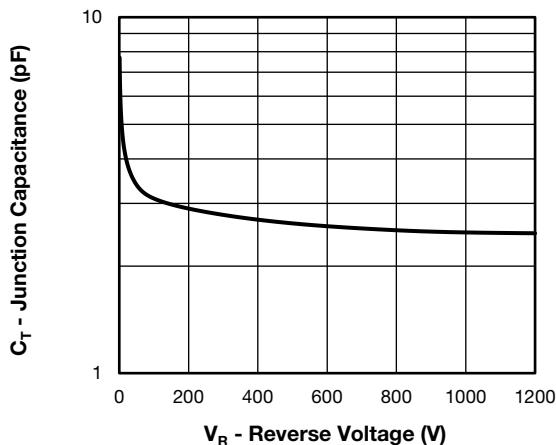


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

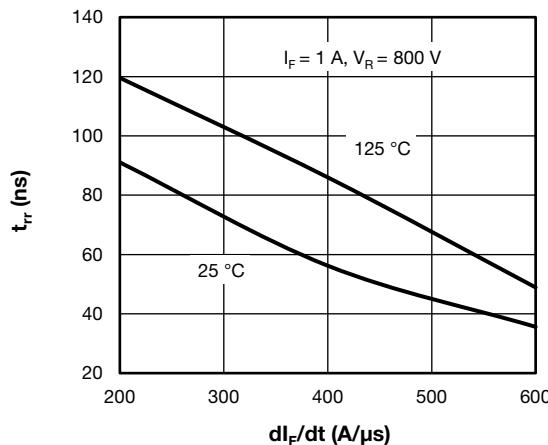


Fig. 6 - Typical Reverse Recovery Time vs.  $dI_F/dt$

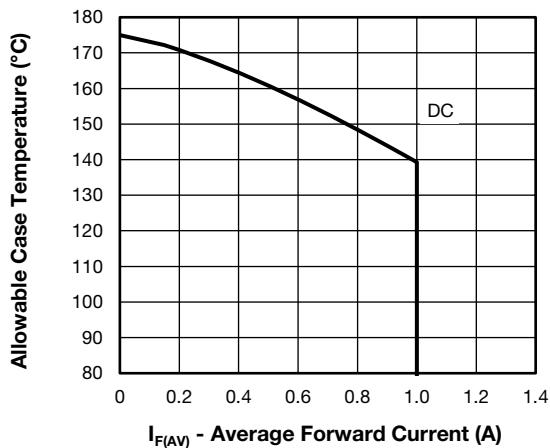


Fig. 4 - Maximum Allowable Case Temperature vs. Average Forward Current

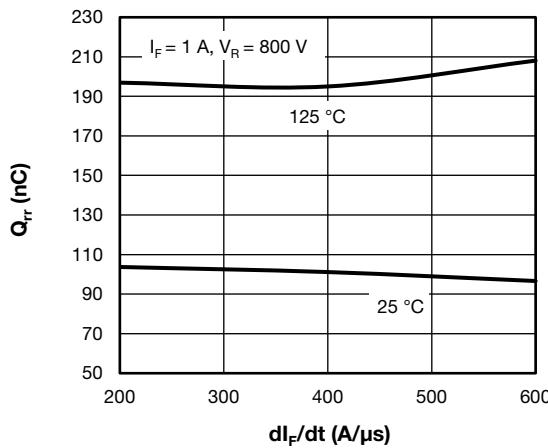


Fig. 7 - Typical Stored Charge vs.  $dI_F/dt$

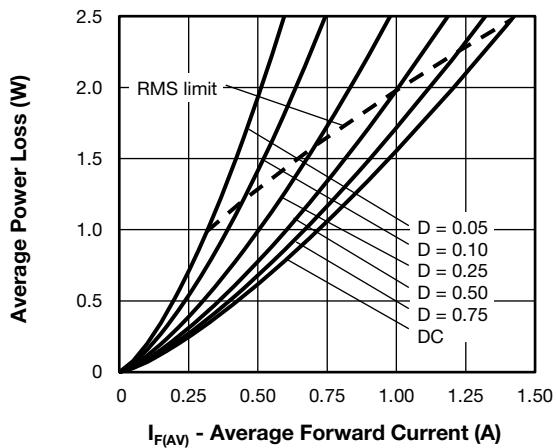


Fig. 5 - Forward Power Loss Characteristics

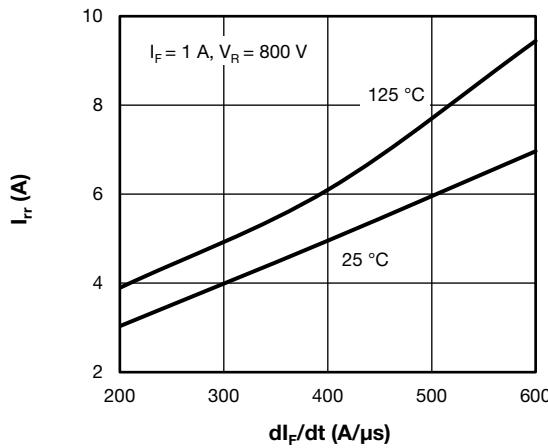


Fig. 8 -  $I_{rr}$  (A) vs.  $dI_F/dt$

#### Note

- (1) Formula used:  $T_C = T_J - (P_d + P_{dREV}) \times R_{thJC}$ ;
- $P_d$  = forward power loss =  $I_{F(AV)} \times V_{FM}$  at  $(I_{F(AV)}/D)$  (see fig. 5);
- $P_{dREV}$  = inverse power loss =  $V_{R1} \times I_R (1 - D)$ ;  $I_R$  at  $V_{R1}$  = rated  $V_R$

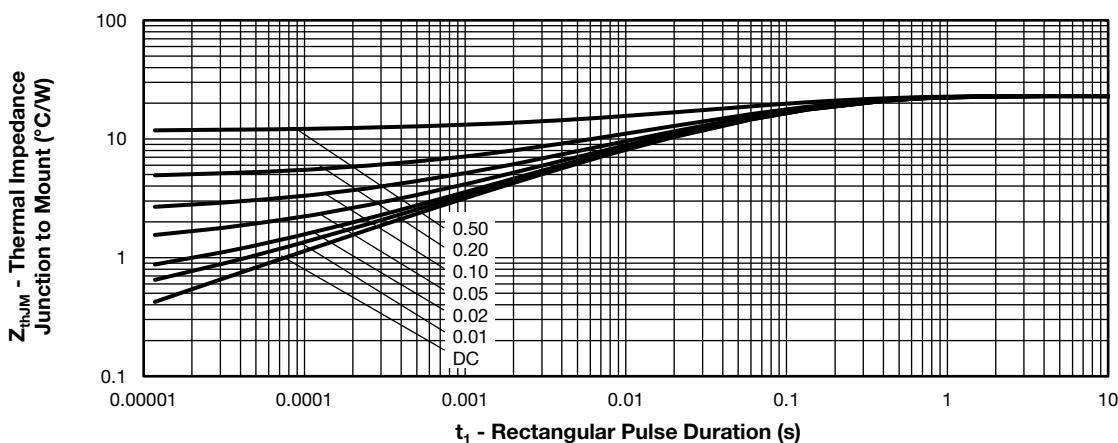


Fig. 9 - Transient Thermal Impedance, Junction to Case

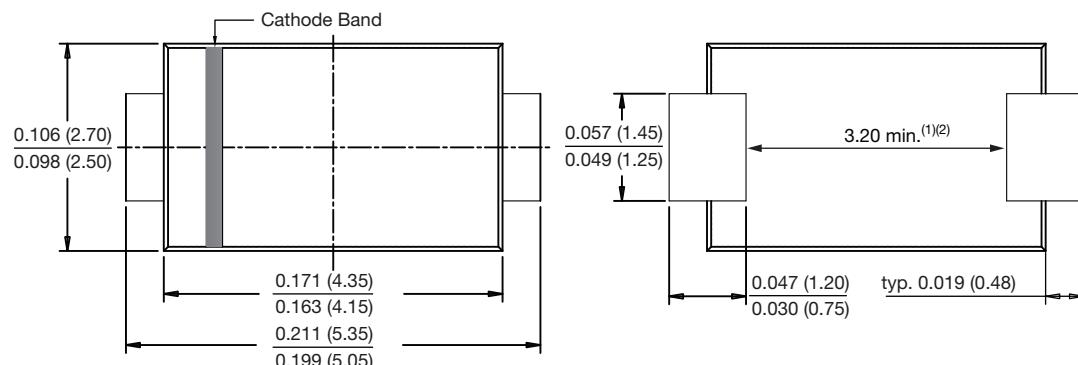
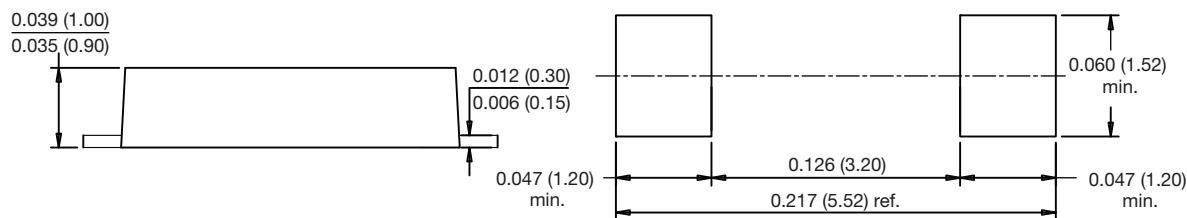
## ORDERING INFORMATION TABLE

Device code	VS-	E	7	J	X	01	12	H	M3
	(1)	(2)	(3)	(4)	(5)	(6)	(7)	(8)	(9)

- (1)** - Vishay Semiconductors product
- (2)** - Circuit configuration:  
E = single diode
- (3)** - 7 = FRED generation 7
- (4)** - J = SlimSMA package
- (5)** - Process type,  
X = hyperfast recovery
- (6)** - Current rating (01 = 1 A)
- (7)** - Voltage code (12 = 1200 V)
- (8)** - H = AEC-Q101 qualified
- (9)** - M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

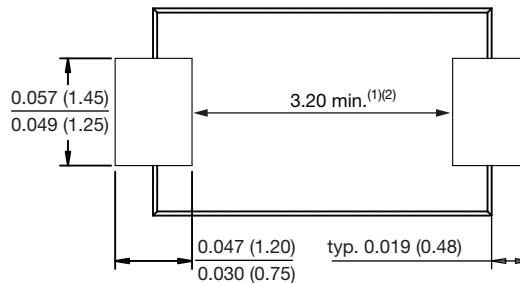
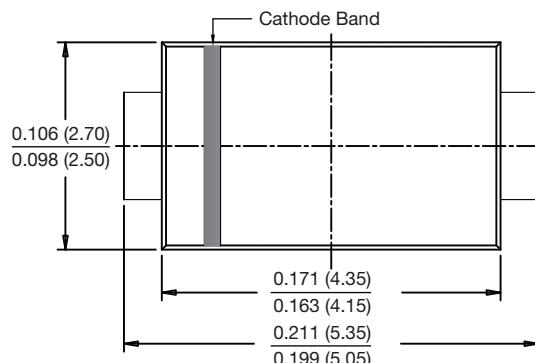
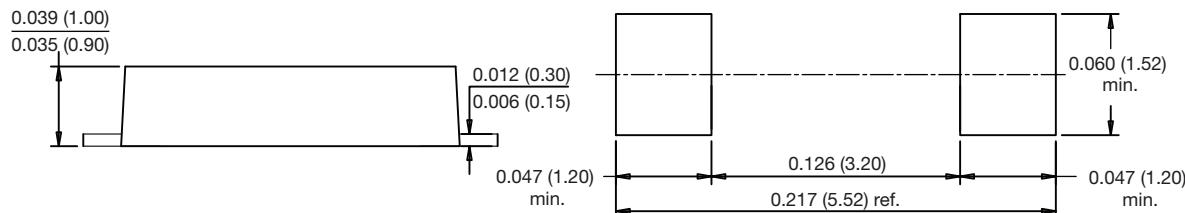
ORDERING INFORMATION (Example)			
PREFERRED P/N	QUANTITY PER REEL	BASE QUANTITY	PACKAGING DESCRIPTION
VS-E7JX0112HM3/H	3500	3500	7" diameter plastic tape and reel
VS-E7JX0112HM3/I	14 000	14 000	13" diameter plastic tape and reel

LINKS TO RELATED DOCUMENTS	
Dimensions	<a href="http://www.vishay.com/doc?97278">www.vishay.com/doc?97278</a>
Part marking information	<a href="http://www.vishay.com/doc?95562">www.vishay.com/doc?95562</a>
Packaging information	<a href="http://www.vishay.com/doc?88869">www.vishay.com/doc?88869</a>

**DIMENSIONS** in inches (millimeters)

**Recommended Mounting Pad Layout**

**Notes**

- (1) Minimum creepage distance is defined and guaranteed by design
- (2) For high voltage applications, end users should consider the relevant guidelines and normative on creepage and clearance distances between device terminals and PCB pads.

## SlimSMA HV (DO-221AC)

**DIMENSIONS** in inches (millimeters)

**Recommended Mounting Pad Layout**

**Notes**

- (1) Minimum creepage distance is defined and guaranteed by design
- (2) For high voltage applications, end users should consider the relevant guidelines and normative on creepage and clearance distances between device terminals and PCB pads.

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